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(71) Applicant: PHOTOBIT CORPORATION [US/US]; 7th floor, 135 North Robles Avenue, Pasadena, CA 91101 (US).

(72) Inventor: FOSSUM, Eric, R.; 5556 Pinecone Road, La Crescenta, CA 91224 (US).

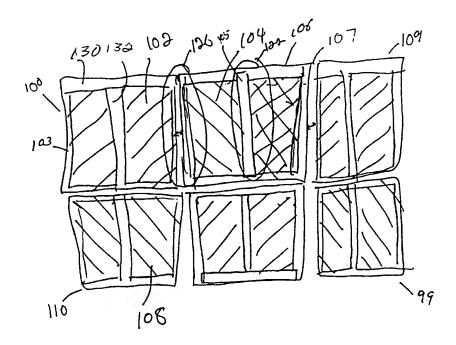
(74) Agent: HARRIS, Scott, C.; Fish & Richardson P.C., Suite 1400, 4225 Executive Square, La Jolla, CA 92037 (US).

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(54) Title: THREE-SIDED BUTTABLE CMOS IMAGE SENSOR



(57) Abstract

An image sensor chip (100) is formed with the image sensor abutting up to three edges of the chip. Certain parts of the row logic (132) which are required to be adjacent to each of the rows are placed into the array (102), in place of certain pixels of the array. Those missing pixels are then interpolated.

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### THREE-SIDED BUTTABLE CMOS IMAGE SENSOR

### **BACKGROUND**

Each chip producer, or "foundry", often has its own set of rules regarding the sizes of chips that can be made in that foundry. A common limit is, for example, 20 x 20 mm<sup>2</sup>. It is relatively difficult to form a large format image sensor, i.e., one larger than that.

Active pixel sensors have integrated amplifiers and other logic formed on the same substrate with the image sensor chip. This obviates certain problems that are associated with charge-coupled devices. The typical active pixel sensor chip has logic along at least two edges of the chip. The other edges of the chip are typically formed with "guard rings" around the edge of the image sensor.

### SUMMARY

According to this system as disclosed herein, a
large format image sensor is formed from multiple,
smaller, sensor chips. These chips are preferably active
pixel sensors that require logic on chip to be associated
with the pixels of the image sensor.

Certain parts of the control structure, e.g., the
25 row addressing mechanism, needs to be individually
associated with the rows of the image sensor. In a
typical active pixel sensor, these parts were located
along certain edges of the chip to avoid the otherwise
need to run a large number of lines across the image
30 sensor to the rows. Other such structure can include a
buffer to sample and hold results from the pixels, and
other associated row structure.

Previous active pixel image sensors formed a continuous rectangle at some area on the chip. At least two of the other edges were masked by the support circuitry.

The presently-disclosed system goes against this established teaching. The chip driver circuitry is formed into the shape of two pixel pitches. The circuitry placed in a central, adjacent two columns in the image sensor. This leaves three sides of the sensor array being close to the edge of the chip, and hence buttable to other similar chips. The multiple butted chip assembly is used to obtain a large format image.

The missing two pixels in the center of the array are interpolated from the neighboring sensor signals by using standard software.

# BRIEF DESCRIPTION OF THE DRAWINGS

These and other aspects of the invention will now be described with reference to the attached drawings, in which:

20 Figure 1 shows a preferred embodiment with a plurality of butted chips;

Figure 2 shows a close up of the butted area; Figure 3 shows the layout of the driver circuit.

# DESCRIPTION OF THE PREFERRED EMBODIMENT

An image sensor of the preferred embodiment is shown in FIG. 1.

FIG. 1 shows six of the specially-configured image sensor chips butted against each other. Each chip is preferably rectangular, although more generally, each of the chips needs to have a first set of parallel edges, and a second set of parallel edges. Each of the chips has an image sensor portion and a control portion. The control portion includes a centralized control portion

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130 adjacent a blocked edge of the chip, and a row-local control portion 132. The row-local control portion 132 runs up the center of the image sensor area 102, masking a central two pixels of the image sensor.

The image sensor portions 102 of the various separated chips are shown hatched in FIG. 1. Each image sensor is surrounded by a guard ring 103 that protects the image sensor, and biases the image sensor portion as appropriate. The guard ring is typically about 40  $\mu m$  in size.

There can be a small space 107 between the two adjacent chips 106, 109 due to the roughness of the edges. The small space is typically of the order of  $\mu m$ .

Hence, the adjacent image sensor areas abut

15 against each other with a separation equal to two guard rings (e.g., 80 µm), and the roughness space. If 40µm pixels are used, then the distance between the adjacent image sensor areas is within 2-4 pixels. This distance between adjacent image sensor areas is preferably small

20 enough that the missing pixels can be interpolated using standard missing pixel interpolation techniques.

Preferably, the distance is less than 2 pixels.

Similarly, image sensor area 102 also abuts against image sensor area 108 of chip 110. As can be seen, the image

25 sensor areas of each of the chips abut against each

FIG. 2 shows a close up in the area 120. The pixel columns 200 and 202 are located in the chip 100, as is the guard ring 103. The pixel columns 204 and 206, and the guard ring 208, are located in the chip 106. A small space 210 is located between the chips.

Generically, the image sensor should extend up to the edge, which means that no circuitry other than the guard ring is formed between the image sensor and the

other.

edge of the substrate. More preferably, the image sensor comes within 1 pixel pitch of the edge, thereby allowing interpolation to reconstruct any missing pixels.

Hence, the pixels 204 are those adjacent pixels

5 202 or separated by a space that is preferably less than
one - two pixels wide. The array of image sensors 99
therefore forms a system where each pixel is separated
from each adjacent pixel in the adjacent image sensor by
an amount that is small enough to allow interpolation of
10 the missing space, to thereby obtain an uninterrupted
image.

FIG. 3 shows a close up of the area 122 in FIG. 1. The center two pixels of the image sensor include drivers 300, 302 for each of the pixel rows. These can be bit 15 decoders to select the rows, or shift registers which select one row after another. SRAM 304 stores temporary results, and also buffers the information as needed. Connections 306 can couple commands to the row circuitry. The overall chip driver 310 can be the same as 20 conventional, including A/D converters for each column and the like. Element 312 also preferably include a twopixel interpolator that is used to interpolate for the missing pixels at areas 105 and 107. Pixel interpolation is well known in the art, and is described, for example, 25 in US Patent no. 4,816,913. More preferably, the pixel interpolation is done in software.

Although only a few embodiments have been described in detail above, other embodiments are contemplated and are intended to be encompassed within the following claims. For example, the row support circuitry can be different in shape than the described system. In addition, other modifications are contemplated and are also intended to be covered. For example, while this system suggests the row-drivers being in the center of the image sensor, they could be off

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center in a location, for example, that is statistically less likely to matter in the final image. Center is preferred, since this equally spaces the pixel gaps between chips and in the chip center.

image sensors,

### What is claimed is:

A CMOS image sensor circuit, comprising:
 a first CMOS image sensor substrate, said
 substrate having an image sensor portion arranged in an
 array of rows and columns, and image sensor logic on said
 substrate, said logic being electrically connected to
 said image sensor portion, said image sensor logic

individually, and chip logic associated with parts of said image sensor other than said rows individually,

including row logic associated with each of said rows

said substrate formed to have at least a first set of parallel edges including a first edge and a second edge, and a second set of parallel edges, different than said first set of parallel edges, said second set of parallel edges including a third edge and a fourth edge,

said image sensor extending between said first edge, said second edge, and said third edge, with no circuitry being located between said image sensor and any of said first, second or third edges, such that a first area adjacent said first edge of the chip includes first pixels of the image sensor, a second area adjacent said second edge of the chip includes image sensors, and a third area adjacent said third edge of the chip includes

said row logic being physically located inside said image sensor in place of a plurality of pixels of the array forming said image sensor.

2. A circuit as in claim 1 wherein said row logic is formed in place of two columns of the array forming the active pixel sensor.

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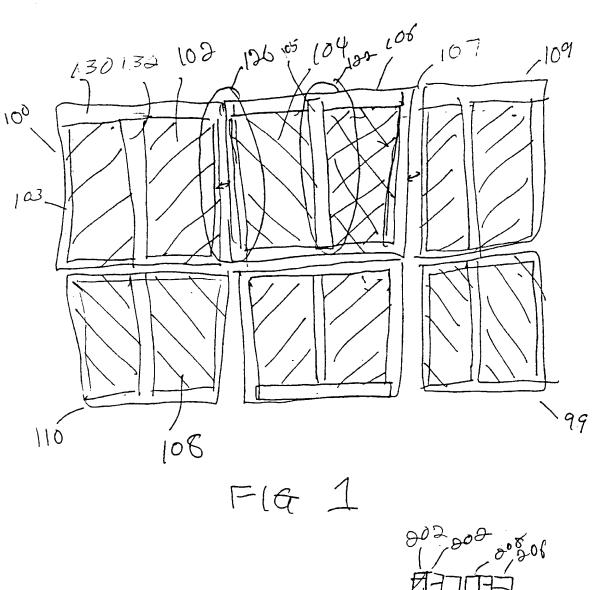
- 7 -

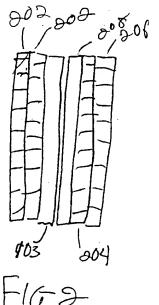
- 3. A circuit as in claim 1 wherein said image sensor extends within two pixel pitches of first, second, and third edges of the chip.
- 4. A circuit as in claim 3 wherein said first and second edges are perpendicular to said third and fourth edges.
- 5. A circuit as in claim 1 further comprising an interpolation element, operating to interpolate pixels which would have impinged on areas of said image sensor portion.
- 6. A circuit as in claim 1 wherein said row logic is in the center of the plurality of pixels forming the image sensor.
- 7. A circuit as in claim 1 wherein the ends of 5 the image sensor includes a guard ring.
  - 8. A method of operating a large format image sensor, comprising:

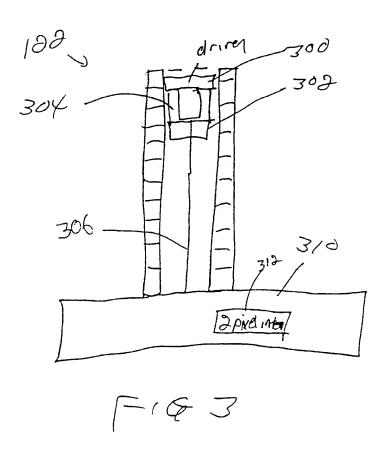
first obtaining an image sensor chip which has first and second edges where said image sensor comes 10 within two pixel pitches of said first and second edges, and includes row selecting logic in place of a plurality of central pixels of the image sensor;

abutting said image sensor chip against a similar image sensor chip of corresponding construction; and

interpolating missing pixels caused by both said row select logic and by spaces between said image sensor chips.







## INTERNATIONAL SEARCH REPORT

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1	SSIFICATION OF SUBJECT MATTER							
IPC(6) :H04N 1/40, 5/30, 9/07 US CL :250/208.1; 257/231, 443; 348/282, 302								
According to International Patent Classification (IPC) or to both national classification and IPC								
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1	documentation searched (classification system followed by classi-	fication symbols)						
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Electronic	data base consulted during the international search (name of dat	a base and, where practicable,	search terms used)					
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C. DOC	CUMENTS CONSIDERED TO BE RELEVANT							
Category*	Citation of document, with indication, where appropriate,	of the relevant passages	Relevant to claim No.					
A	US 4,668,333 A (TANDON ET AL) 26 May	1987 (26/05/87), see	1-8					
	entire document.							
A	US 4,698,131 A (ARAGHI ET AL) 06 October entire document.	1-8						
Α	US 5,031,032 A (PERREGAUX ET AL) 09 J see entire document.	uly 1991 (09/07/91),	1-8					
	see chare obtained.							
A	US 5,282,057 A (MAILLOUX ET AL) 25 Janu see entire document.	nary 1994 (25/01/94),	1-8					
Furti	her documents are listed in the continuation of Box C.	See patent family annex.						
• Sp		later document published after the intern date and not in conflict with the applica						
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#### **B. FIELDS SEARCHED**

Minimum documentation searched Classification System: U.S.

250/208.1; 257/231, 443; 348/282, 302; 250/214A, 214R, 214.1; 257/225, 232, 291, 292, 293, 431, 444, 452; 348/281, 283, 272, 294, 300, 301

#### B. FIELDS SEARCHED

Electronic data bases consulted (Name of data base and where practicable terms used):

#### APS USPAT FILE

search terms: image array, image sensor, imaging array, imaging sensor, large format, interpolated, interpolated, interpolating, pixel, pixels, abutting, CCD

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